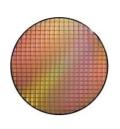


Wafer made yesterday
All NMOS are "slow"
All PMOS are "nominal"
All R are nominal
All C are "fast"



Wafer made today
All NMOS are "fast"
All PMOS are "fast"
All R are nominal
All C are "slow"

Parameter	"Slow"	"Nominal"	"Fast"
V_{t}	0.4V	0.3V	0.2V
μC_{ox} (NMOS)	$240~\mu\text{A/V}^2$	$300 \mu A/V^2$	$360~\mu\text{A/V}^2$
μC_{ox} (PMOS)	80 μA/V²	100 μA/V ²	120 μ A/V ²
R_{poly}	60Ω/□	50Ω/□	40Ω/□
R _{nwell}	1.4 kΩ/□	1 kΩ/□	0.6 kΩ/□
C _{MIM}	$1.15~\text{fF}/\mu\text{m}^2$	$1 \text{ fF/}\mu\text{m}^2$	$0.85 \text{ fF}/\mu\text{m}^2$